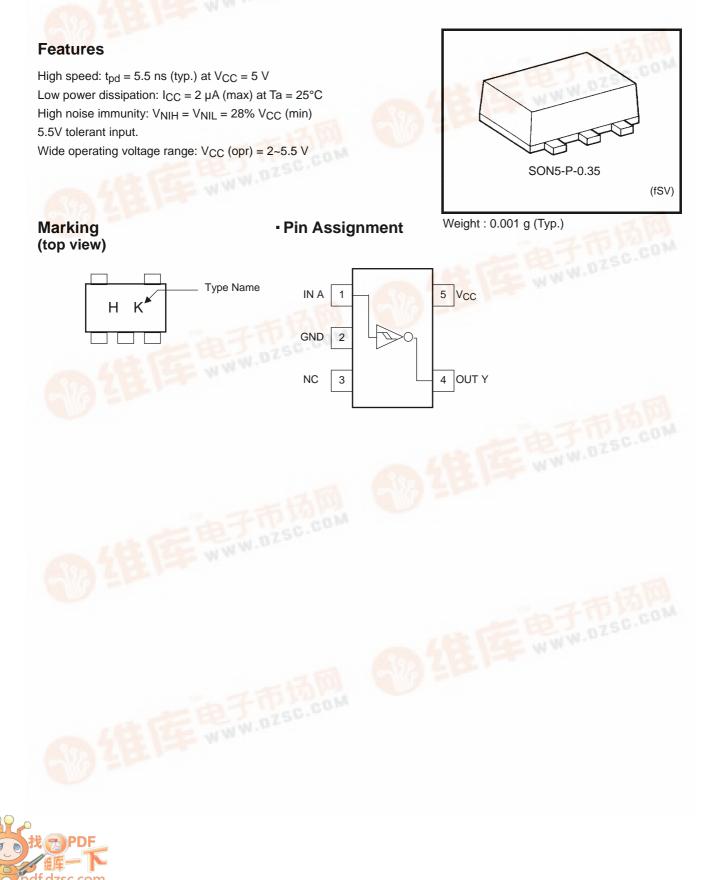


TC7SH14FS

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic



SCHMITT INVERTER

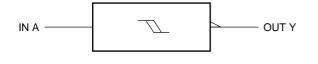


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Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V _{CC}	-0.5~7.0	V
DC input voltage	V _{IN}	-0.5~7.0	V
DC output voltage	V _{OUT}	-0.5~V _{CC} + 0.5	V
Input diode current	IIK	-20	mA
Output diode current	I _{OK}	±20	mA
DC output current	IOUT	±25	mA
DC V _{CC} /ground current	ICC	±50	mA
Power dissipation	PD	50	mW
Storage temperature	T _{stg}	-65~150	°C

Logic Diagram



А	Y
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Truth Table

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Recommended Operating Conditions

Characteristics	Symbol	Rating	Unit
Supply voltage	V _{CC}	2.0~5.5	V
Input voltage	V _{IN}	0~5.5	V
Output voltage	VOUT	0~V _{CC}	V
Operating temperature	T _{opr}	-40~85	°C

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Electrical Characteristics

DC Characteristics

Characteristics Symbol Test Circuit		Test				Ta = 25°C		Ta = -40~85°C			
		Test Condition V _{CC} (V)			Min	Тур.	Max	Min	Max	Unit	
Positive					3.0			2.20		2.20	
Threshold	V_{P}		—		4.5	_		3.15	_	3.15	V
voltage					5.5	—		3.85	_	3.85	
Negative					3.0	0.90		—	0.90	_	
Threshold	VN	—			4.5	1.35	_	—	1.35	_	V
voltage					5.5	1.65		—	1.65	_	
TT / ·					3.0	0.30		1.20	0.30	1.20	
Hysteresis voltage	VH				4.5	0.40		1.40	0.30	1.40	V
voltago					5.5	0.30	—	1.60	0.30	1.60	
			V _{IN} = VIL	I _{OH} = -50 μA	2.0	1.9	2.0	_	1.9	_	V
					3.0	2.9	3.0	_	2.9	_	
High-level output voltage	V _{OH}	н —			4.5	4.4	4.5	_	4.4	_	
				I _{OH} = -4 mA	3.0	2.58	_	_	2.48	_	
			I _{OH} = -8 mA	4.5	3.94			3.80			
		V _{OL} —	VIN = VIH	I _{OL} = 50 μA	2.0	—	0.0	0.1	—	0.1	- - - -
					3.0	_	0.0	0.1	_	0.1	
Low-level output voltage Vo	V _{OL}				4.5	—	0.0	0.1	—	0.1	
				I _{OL} = 4 mA	3.0	—		0.36	—	0.44	
				I _{OL} = 8 mA	4.5	_		0.36	_	0.44	
Input leakage current	I _{IN}	_	$V_{IN} = 5.5 V \text{ or GND}$		0~ 5.5	_	_	±0.1	_	±1.0	μΑ
Quiescent supply current	Icc	_	$V_{IN} = V_{CC}$ or GND		5.5	—	—	2.0	—	20.0	μΑ

Characteristics Symbol	Symbol	Test	٦	Test Conditio	est Condition		Ta = 25°C			Ta = -40~85°C	
	Symbol	Circuit	it	V _{CC} (V)	C _L (pF)	Min	Тур.	Max	Min	Max	Unit
				3.3 ± 0.3	15	_	8.3	12.8	1.0	15.0	ns
	tpLH				50	_	10.8	16.3	1.0	18.5	
	t _{pHL}	_		5.0 ± 0.5	15	_	5.5	8.6	1.0	10.0	
					50	_	7.0	10.6	1.0	12.0	
Input capacitance	C _{IN}	_		—		_	4	10	_	10	pF
Power dissipation capacitance	C _{PD}	—			(Note)		14		_		pF

AC Characteristics (Input: $t_r = t_f = 3 ns$)

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

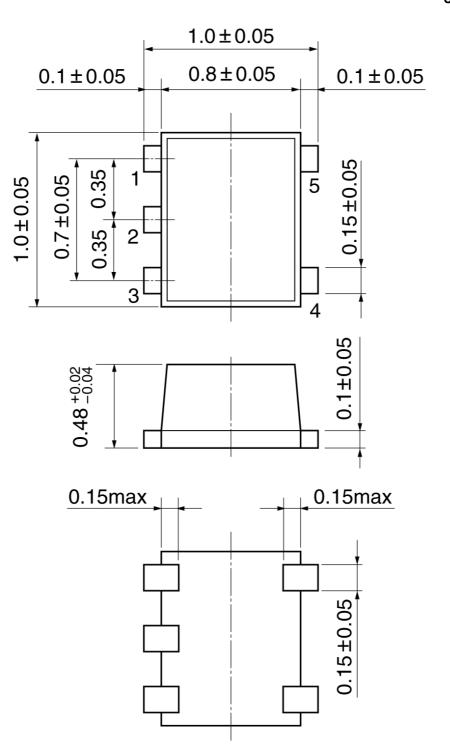
 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

TOSHIBA

Package Dimensions

SON5-P-0.35

Unit:mm



Weight: 0.001 g (typ.)

TOSHIBA

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Handbook" etc..

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